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April 2008

FDS5351

N-Channel PowerTrench[®] MOSFET 60V, 6.1A, $35m\Omega$

Features

- Max $r_{DS(on)} = 35m\Omega$ at $V_{GS} = 10V$, $I_D = 6.1A$
- Max $r_{DS(on)} = 42m\Omega$ at $V_{GS} = 4.5V$, $I_D = 5.5A$
- High performance trench technology for extremely low r_{DS(on)}
- 100% UIL Tested
- RoHS Compliant

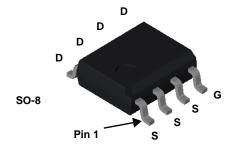


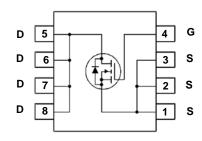
General Description

This N-Channel MOSFET is produced using Fairchild Semiconductor's advanced Power Trench® process that has been especially tailored to minimize the on-state resistance and yet maintain superior switching performance.

Application

- Inverter Switch
- Synchronous Rectifier
- Load Switch





MOSFET Maximum Ratings $T_A = 25$ °C unless otherwise noted

Symbol	Parameter		Ratings	Units
V _{DS}	Drain to Source Voltage		60	V
V_{GS}	Gate to Source Voltage		±20	V
	Drain Current -Continuous		6.1	^
'D	-Pulsed		30	A
E _{AS}	Single Pulse Avalanche Energy	(Note 3)	73	mJ
D	Power Dissipation T _A = 25°C	(Note 1a)	5	W
P_{D}	Power Dissipation $T_A = 25^{\circ}C$	(Note 1b)	2.5	VV
T _J , T _{STG}	Operating and Storage Junction Temperature Range	-55 to +150	°C	

Thermal Characteristics

$R_{\theta JC}$	Thermal Resistance, Junction to Case	(Note 1)	25	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1a)	50	C/VV

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDS5351	FDS5351	SO-8	13"	12mm	2500units

Electrical Characteristics $T_J = 25^{\circ}C$ unless otherwise noted **Parameter**

Off Char	racteristics					
BV_{DSS}	Drain to Source Breakdown Voltage	$I_D = 250 \mu A, V_{GS} = 0 V$	60			V
$\frac{\Delta BV_{DSS}}{\Delta T_{J}}$	Breakdown Voltage Temperature Coefficient	I _D = 250μA, referenced to 25°C		55		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 48V$, $V_{GS} = 0V$			1	μΑ
I _{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 20V, V_{DS} = 0V$			±100	nA

Test Conditions

Min

Тур

Max

Units

On Characteristics

Symbol

V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_D = 250\mu A$	1.0	2.0	3.0	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 250\mu\text{A}$, referenced to 25°C		-6.2		mV/°C
		$V_{GS} = 10V, I_D = 6.1A$		26.5	35.0	
r _{DS(on)}	Static Drain to Source On Resistance	$V_{GS} = 4.5V, I_D = 5.5A$		32.4	42.0	mΩ
		$V_{GS} = 10V$, $I_D = 6.1A$, $T_J = 125$ °C		44.5	58.8	
g _{FS}	Forward Transconductance	$V_{DD} = 5V, I_D = 6.1A$		24		S

Dynamic Characteristics

C _{iss}	Input Capacitance	V 20V V 0V	985	1310	pF
C _{oss}	Output Capacitance	$V_{DS} = 30V, V_{GS} = 0V,$ f = 1MHz	90	120	pF
C _{rss}	Reverse Transfer Capacitance	1 – 111112	50	75	pF
R_g	Gate Resistance	f = 1MHz	1.7		Ω

Switching Characteristics

t _{d(on)}	Turn-On Delay Time	.,	8	16	ns
t _r	Rise Time	$V_{DD} = 30V, I_D = 6.1A, V_{GS} = 10V, R_{GEN} = 6\Omega$	3	10	ns
t _{d(off)}	Turn-Off Delay Time	V _{GS} = 10V, K _{GEN} = 652	21	34	ns
t _f	Fall Time		2	10	ns
Q_g	Total Gate Charge	V _{GS} = 0V to 10V	19	27	nC
Qg	Total Gate Charge	$V_{GS} = 0V \text{ to } 4.5V$ $V_{DD} = 30V,$ $I_{D} = 6.1A$	9	13	nC
Q _{gs}	Gate to Source Charge	1 _D = 0.1A	3		nC
Q _{gd}	Gate to Drain "Miller" Charge		3.5		nC

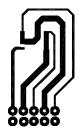
Drain-Source Diode Characteristics

$V_{GS} = 0V, I_{S} = 2.1A$ (Note 2) 0.76 1.2 V_{rr} Reverse Recovery Time $V_{F} = 6.1A, di/dt = 100A/\mu s$ 1 1 2 37 1 38 1 1 1 2 37 1 3 38 1 1 1 3 3 3 3 3 3 3 3 3 3 3 3 3	V	Source to Drain Diode Forward Voltage	$V_{GS} = 0V, I_S = 6.1A$ (Note 2)		0.82	1.3	\/
$I_{\rm F} = 6.1$ A, di/dt = 100A/ μ s	VSD Source to Drain Blode 1 of ward voltage		$V_{GS} = 0V, I_S = 2.1A$ (Note 2)		0.76	1.2	V
	t _{rr}	Reverse Recovery Time	I _F = 6.1A, di/dt = 100A/μs		24	38	ns
	Q _{rr}	Reverse Recovery Charge			15	27	nC

^{1.} R_{θ,JA} is determined with the device mounted on a 1in² pad 2 oz copper pad on a 1.5 x 1.5 in. board of FR-4 material. R_{θ,JC} is guaranteed by design while R_{θ,CA} is determined by the user's board design.



a) 50°C/W when mounted on a 1in² pad of 2 oz copper.



b) 125°C/W when mounted on a minimum pad.

- 2. Pulse Test: Pulse Width < $300\mu s$, Duty cycle < 2.0%.
- 3. UIL condition: Starting T_J = 25°C, L = 3mH, I_{AS} = 7A, V_{DD} = 60V, V_{GS} = 10V.

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Typical Characteristics T_J = 25°C unless otherwise noted

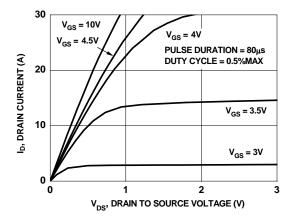


Figure 1. On-Region Characteristics

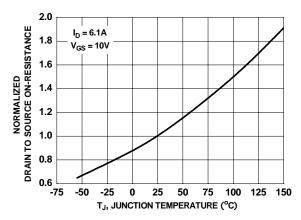


Figure 3. Normalized On-Resistance vs Junction Temperature

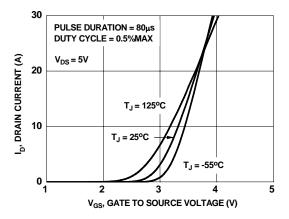


Figure 5. Transfer Characteristics

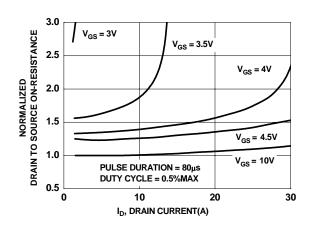


Figure 2. Normalized On-Resistance vs Drain Current and Gate Voltage

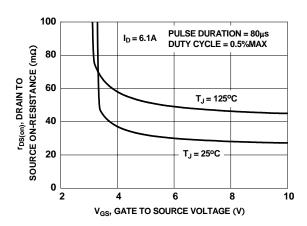


Figure 4. On-Resistance vs Gate to Source Voltage

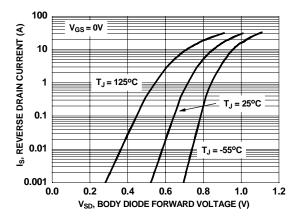


Figure 6. Source to Drain Diode Forward Voltage vs Source Current

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Typical Characteristics T_J = 25°C unless otherwise noted

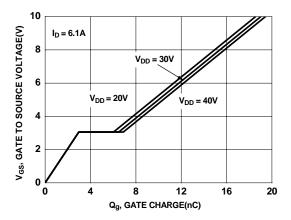


Figure 7. Gate Charge Characteristics

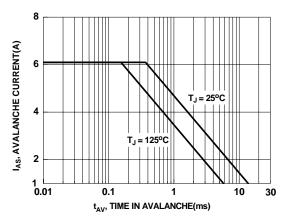


Figure 9. Unclamped Inductive Switching Capability

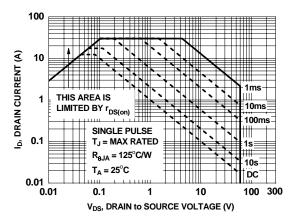


Figure 11. Forward Bias Safe Operating Area

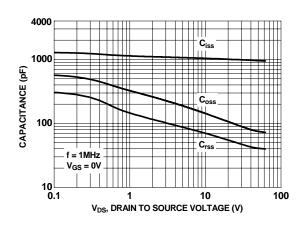


Figure 8. Capacitance vs Drain to Source Voltage

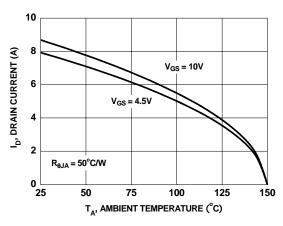


Figure 10. Maximum Continuous Drain Current vs Ambient Temperature

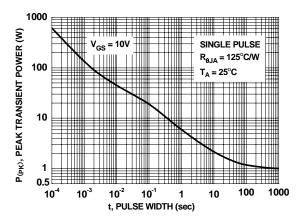


Figure 12. Single Pulse Maximum Power Dissipation

Typical Characteristics $T_J = 25$ °C unless otherwise noted

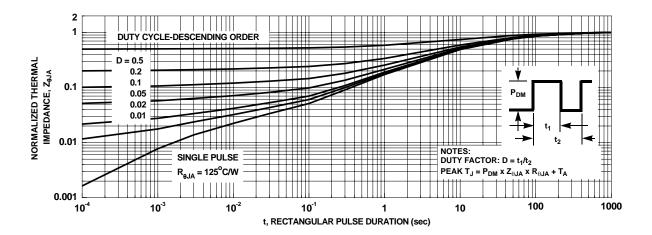


Figure 13. Transient Thermal Response Curve





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No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
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